

RJH60A85RDPP-M0

600V - 15A - IGBT

Application: Inverter

R07DS0811EJ0200

Rev.2.00

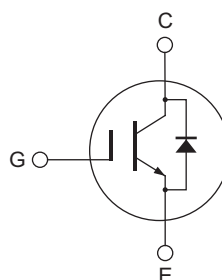
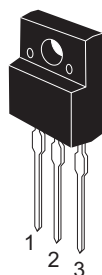
Jul 12, 2012

Features

- Reverse conducting IGBT with monolithic diode
- Short circuit withstand time (5 μ s typ.)
- Low collector to emitter saturation voltage
 $V_{CE(sat)} = 1.5$ V typ. (at $I_C = 15$ A, $V_{GE} = 15$ V, $T_a = 25^\circ\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 160$ ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching
 $t_f = 110$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 15$ A, $R_g = 5$ Ω , $T_a = 25^\circ\text{C}$, inductive load)

Outline

RENESAS Package code: PRSS0003AF-A
(Package name: TO-220FL)



1. Gate
2. Collector
3. Emitter

Absolute Maximum Ratings

($T_a = 25^\circ\text{C}$)

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V_{CES} / V_R	600	V
Gate to emitter voltage		V_{GES}	± 30	V
Collector current	$T_c = 25^\circ\text{C}$	I_C	30	A
	$T_c = 100^\circ\text{C}$	I_C	15	A
Collector peak current		$I_{C(peak)}$ ^{Note1}	60	A
Collector to emitter diode forward current		i_{DF}	15	A
Collector to emitter diode forward peak current		$i_{DF(peak)}$ ^{Note1}	60	A
Collector dissipation		P_C ^{Note2}	39.7	W
Junction to case thermal resistance		θ_{j-c} ^{Note2}	3.15	$^\circ\text{C} / \text{W}$
Junction temperature		T_j	150	$^\circ\text{C}$
Storage temperature		T_{stg}	-55 to +150	$^\circ\text{C}$

Notes: 1. $PW \leq 10$ μ s, duty cycle $\leq 1\%$

2. Value at $T_c = 25^\circ\text{C}$

Electrical Characteristics

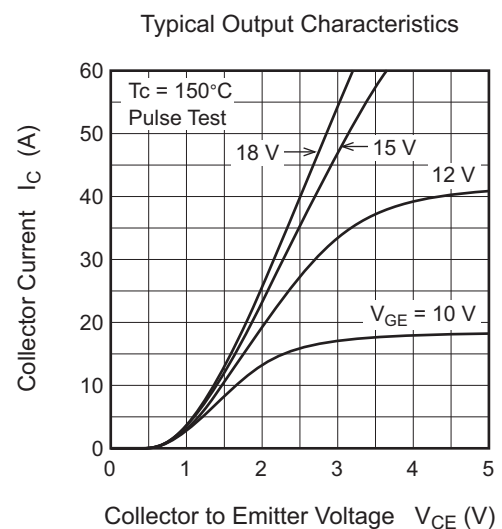
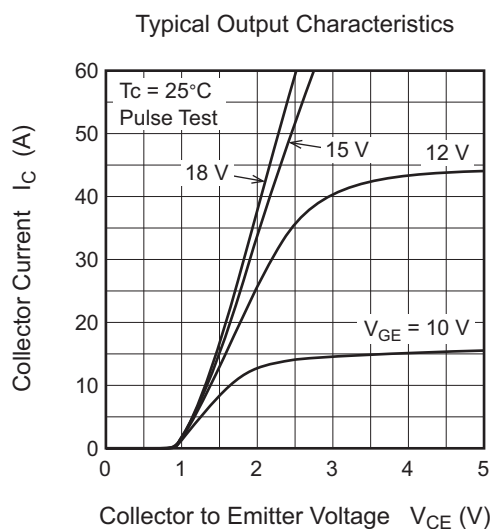
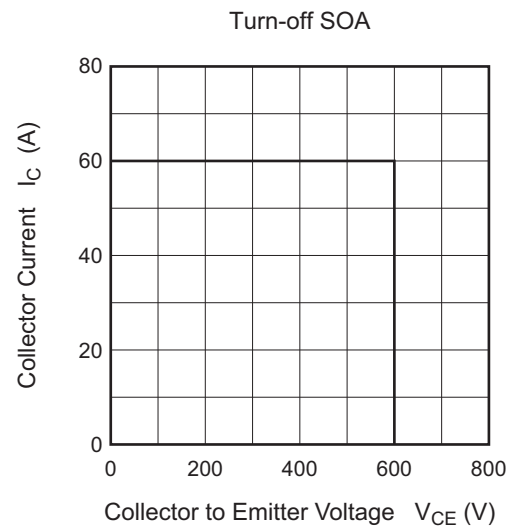
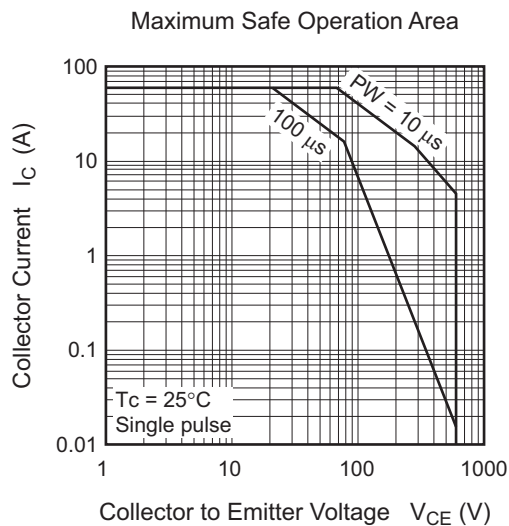
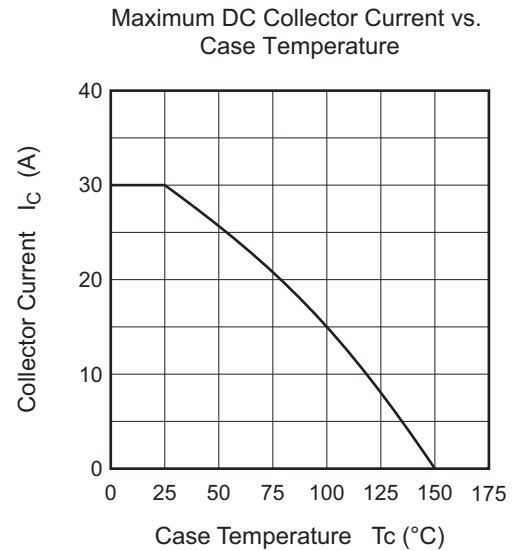
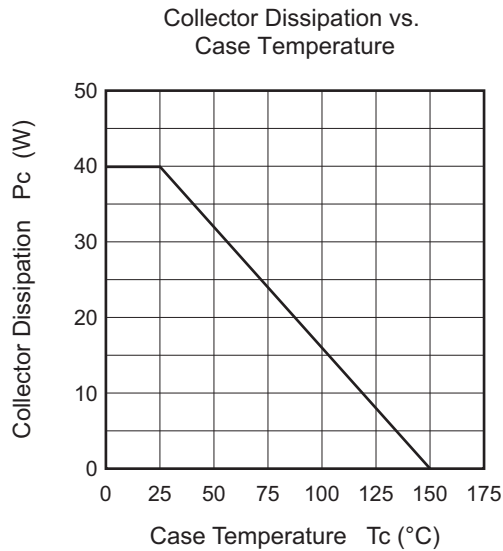
(Ta = 25°C)

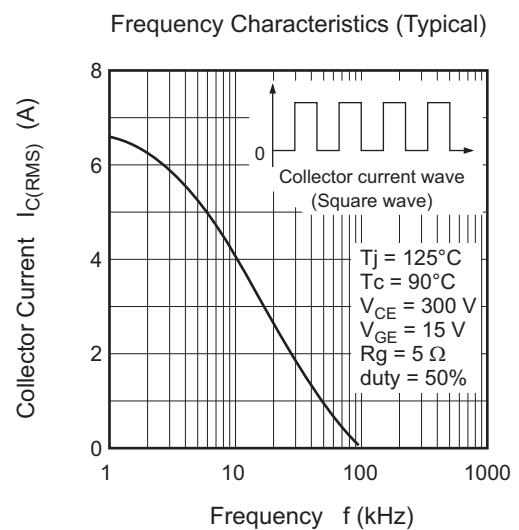
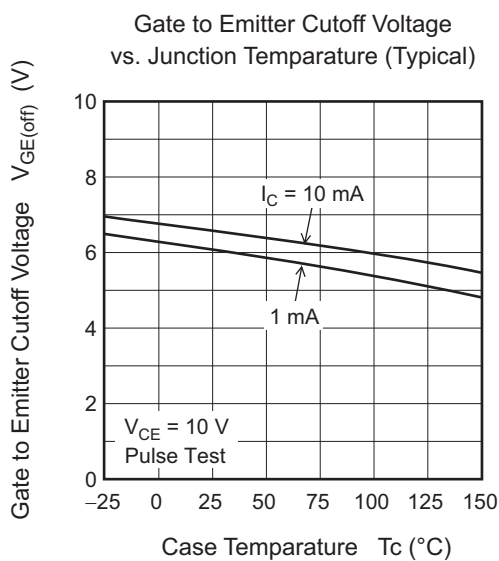
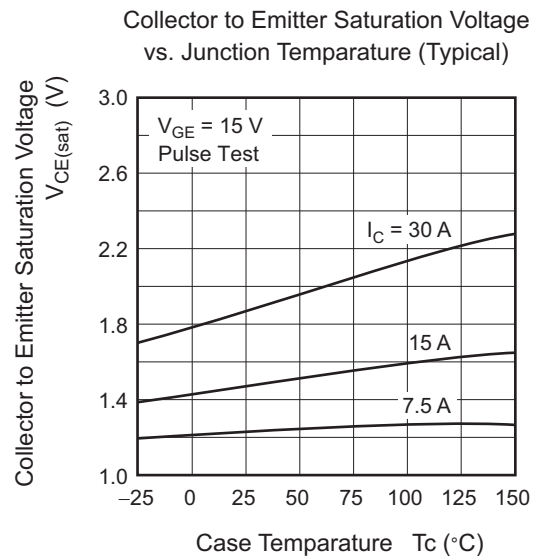
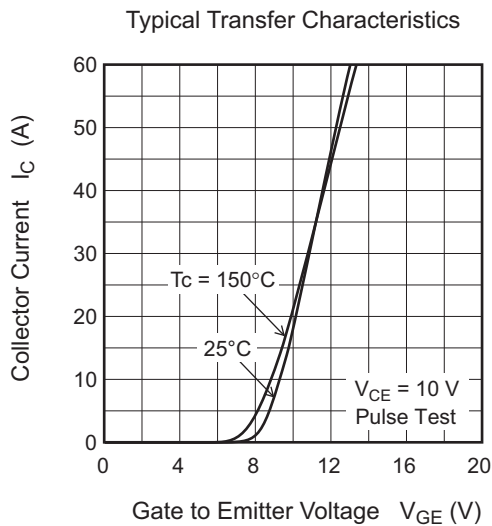
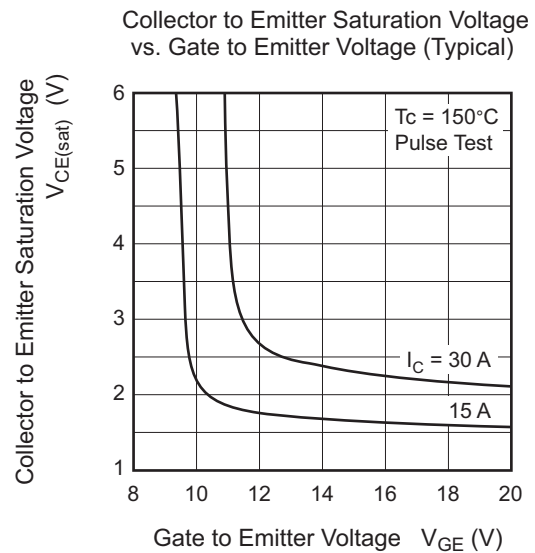
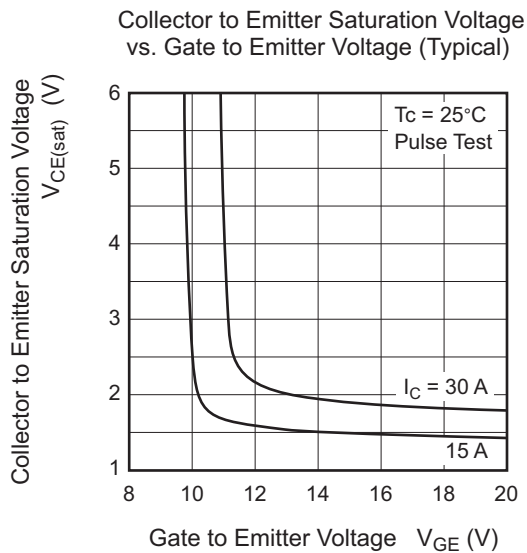
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CES}$	600	—	—	V	$I_C = 10\ \mu A$, $V_{GE} = 0$
Zero gate voltage collector current / diode reverse current	I_{CES} / I_R	—	—	1	μA	$V_{CE} = 600\ V$, $V_{GE} = 0\ V$
Gate to emitter leak current	I_{GES}	—	—	± 100	nA	$V_{GE} = \pm 30\ V$, $V_{CE} = 0\ V$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4.5	—	7.5	V	$V_{CE} = 10\ V$, $I_C = 1\ mA$
Collector to emitter saturation voltage	$V_{CE(sat)}$	—	1.5	1.8	V	$I_C = 15\ A$, $V_{GE} = 15\ V$ ^{Note3}
	$V_{CE(sat)}$	—	1.9	—	V	$I_C = 30\ A$, $V_{GE} = 15\ V$ ^{Note3}
Input capacitance	C_{ies}	—	880	—	pF	$V_{CE} = 25\ V$
Output capacitance	C_{oes}	—	48	—	pF	$V_{GE} = 0\ V$
Reveres transfer capacitance	C_{res}	—	35	—	pF	$f = 1\ MHz$
Total gate charge	Q_g	—	56	—	nC	$V_{GE} = 15\ V$
Gate to emitter charge	Q_{ge}	—	8.4	—	nC	$V_{CE} = 300\ V$
Gate to collector charge	Q_{gc}	—	33	—	nC	$I_C = 15\ A$
Turn-on delay time	$t_{d(on)}$	—	40	—	ns	$V_{CC} = 300V$
Rise time	t_r	—	17	—	ns	$V_{GE} = 15\ V$
Turn-off delay time	$t_{d(off)}$	—	86	—	ns	$I_C = 15\ A$
Fall time	t_f	—	110	—	ns	$R_g = 5\ \Omega$
Turn-on energy	E_{on}	—	0.43	—	mJ	Inductive load
Turn-off energy	E_{off}	—	0.30	—	mJ	
Total switching energy	E_{total}	—	0.73	—	mJ	
Short circuit withstand time	t_{sc}	3.0	5.0	—	μs	$V_{CE} \leq 360\ V$, $V_{GE} = 15\ V$ $T_j = 100^\circ C$

FRD forward voltage	V_F	—	1.7	—	V	$I_F = 15\ A$ ^{Note3}
FRD reverse recovery time	t_{rr}	—	160	—	ns	$I_F = 15\ A$
FRD reverse recovery charge	Q_{rr}	—	0.47	—	μC	$di_F/dt = 100\ A/\mu s$
FRD peak reverse recovery current	I_{rr}	—	7.5	—	A	

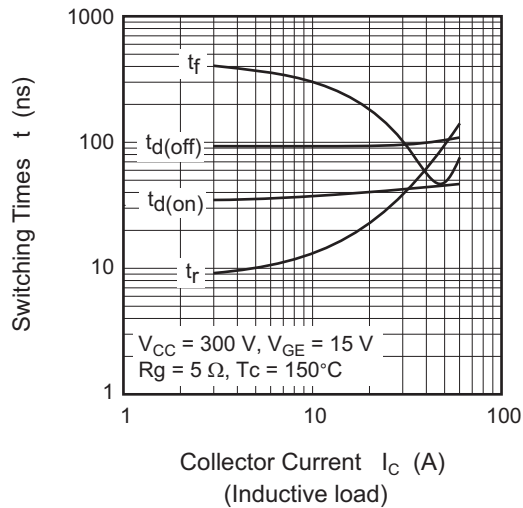
Notes: 3. Pulse test.

Main Characteristics

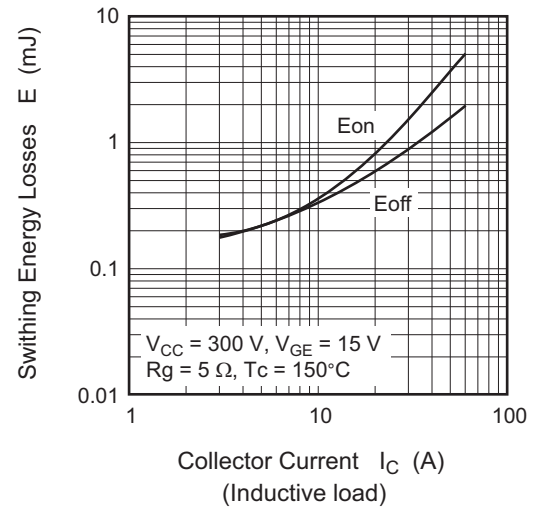




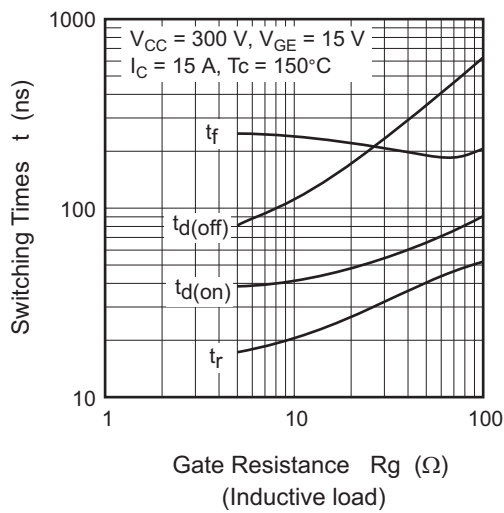
Switching Characteristics (Typical) (1)



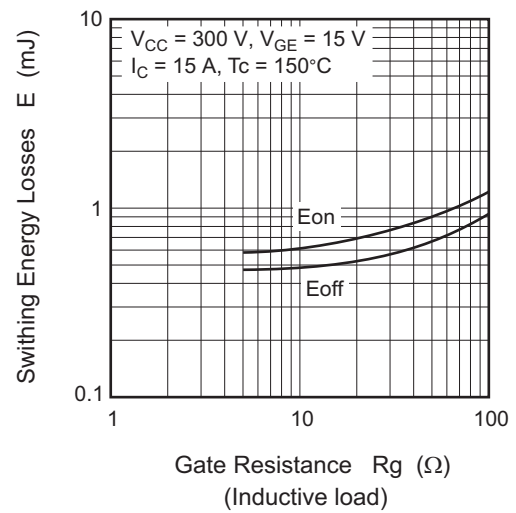
Switching Characteristics (Typical) (2)



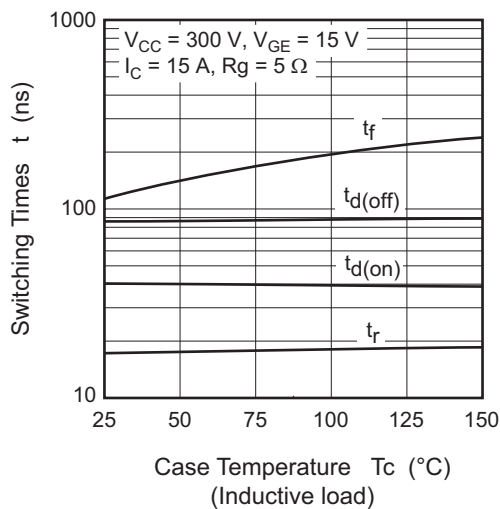
Switching Characteristics (Typical) (3)



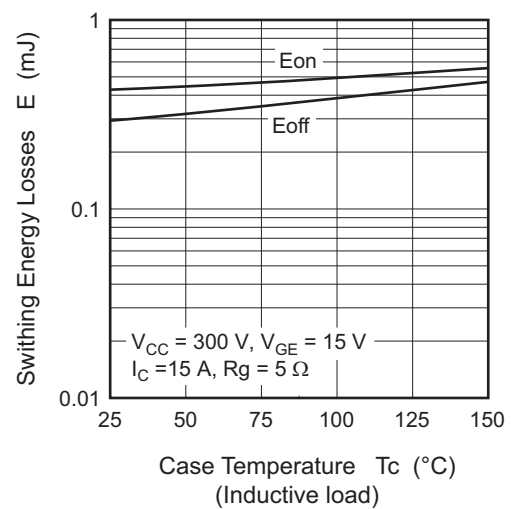
Switching Characteristics (Typical) (4)

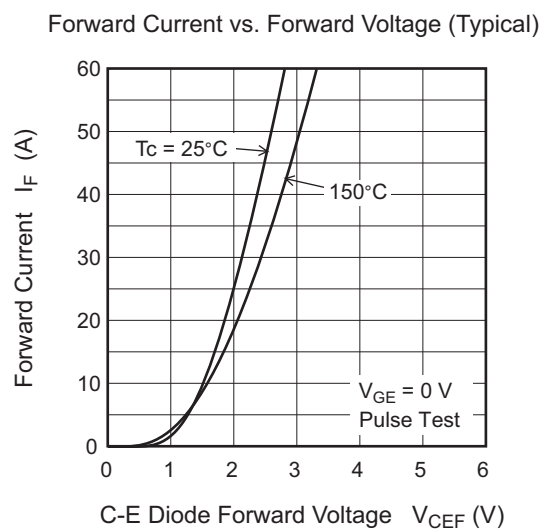
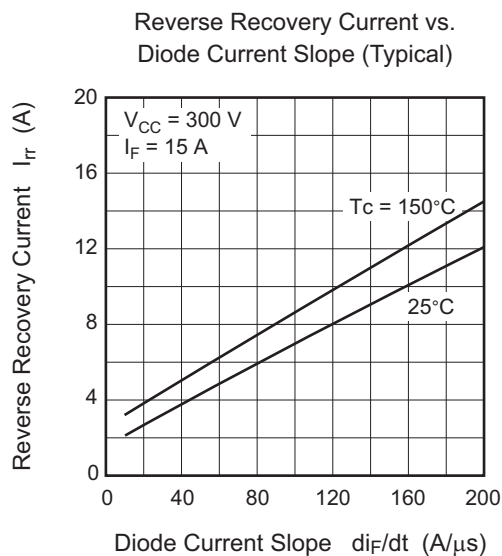
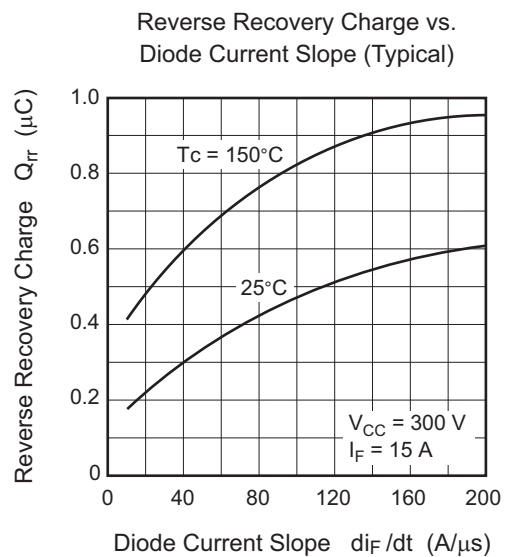
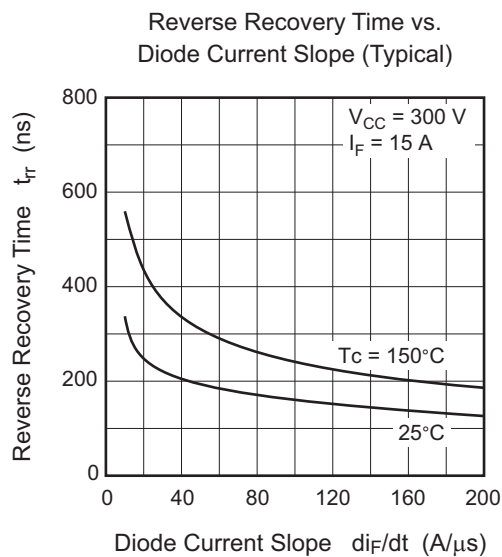
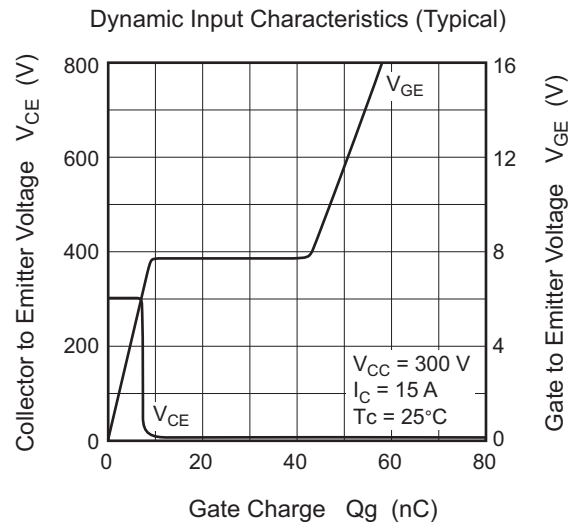
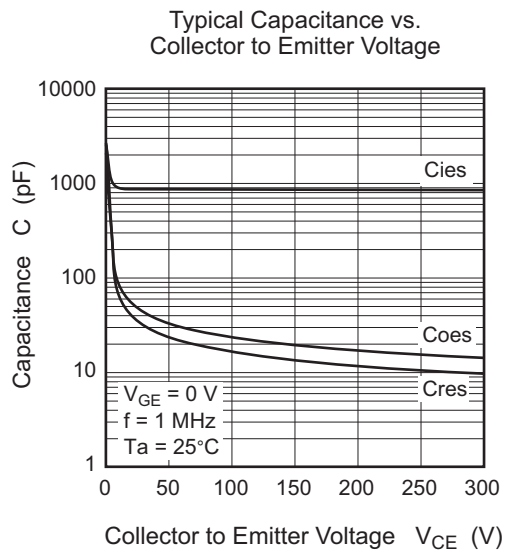


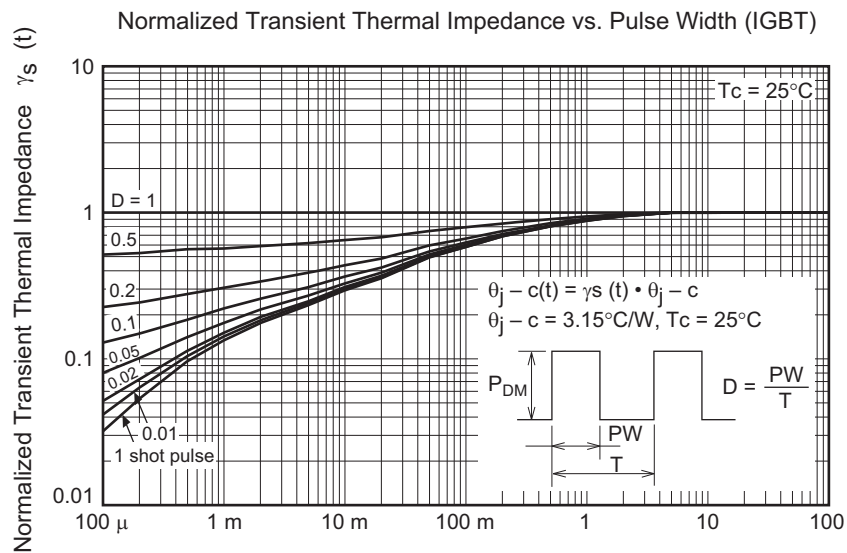
Switching Characteristics (Typical) (5)



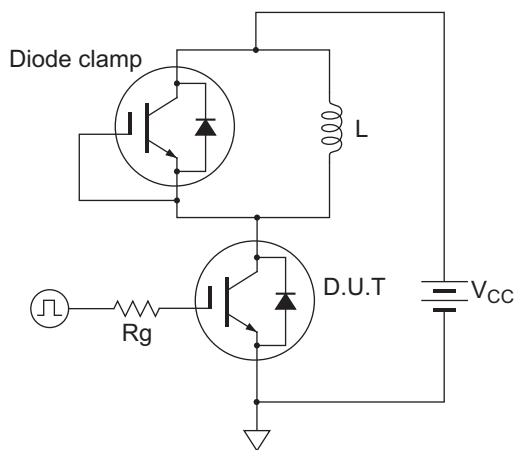
Switching Characteristics (Typical) (6)



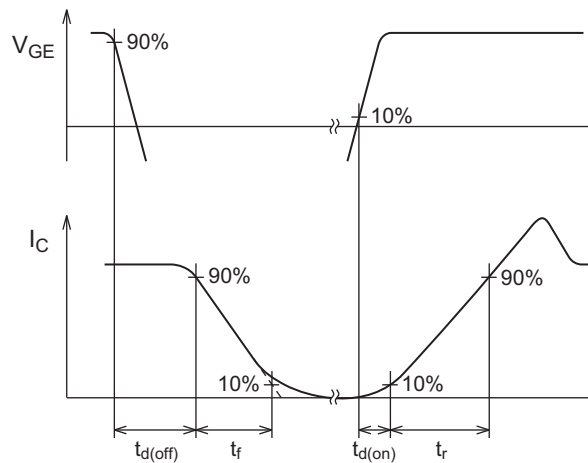




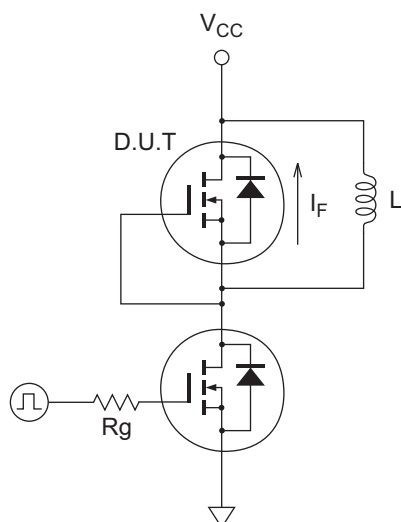
Switching Time Test Circuit



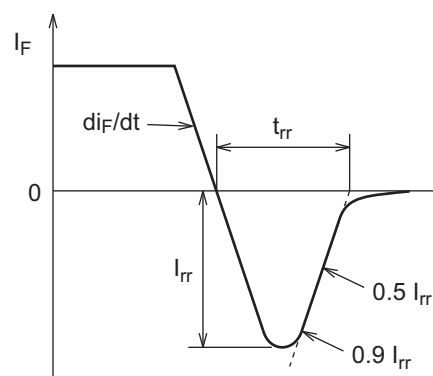
Waveform



Diode Reverse Recovery Time Test Circuit



Waveform



Package Dimension

Package Name	JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]	Unit: mm
TO-220FL	—	PRSS0003AF-A	TO-220FL	1.5g	

Technical drawing of the RJH60A85RDPP-M0 package showing dimensions in mm:

- Top View:
 - Overall width: 10.0 ± 0.3
 - Overall height: 15.0 ± 0.3
 - Distance from top edge to mounting hole center: 3.0 ± 0.3
 - Distance from side edge to mounting hole center: 6.5 ± 0.3
 - Mounting hole diameter: $\phi 3.2 \pm 0.2$
- Side View:
 - Overall height: 12.5 ± 0.5
 - Distance from base to mounting hole center: 3.6 ± 0.3
 - Lead height: 2.8 ± 0.2
 - Lead thickness: 0.40 ± 0.15
- Detail View (Lead):
 - Lead thickness: 0.75 ± 0.15
 - Lead width: 2.54 ± 0.25
 - Lead height: 1.15 ± 0.2
 - Lead width: 2.54 ± 0.25
 - Lead height: 1.15 ± 0.2
 - Lead width: 2.6 ± 0.2
 - Lead height: 4.5 ± 0.2

Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60A85RDPP-M0#T2	600 pcs	Box (Tube)

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Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited
1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada
Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Millboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K.
Tel: +44-1628-585-100, Fax: +44-1628-585-900

Renesas Electronics Europe GmbH
Arcadiastrasse 10, 40472 Düsseldorf, Germany
Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd.
7th Floor, Quantum Plaza, No.27 ZhiChunLu Haidian District, Beijing 100083, P.R.China
Tel: +86-10-8235-1155, Fax: +86-10-8235-7679

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China
Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2886-9318, Fax: +852 2886-9022/9044

Renesas Electronics Taiwan Co., Ltd.
13F, No. 363, Fu Shing North Road, Taipei, Taiwan
Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

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